A Product Line of
Diodes Incorporated

PI6C492150xTQ

High Performance Automotive 2/4 Ports LVDS Fanout Buffer

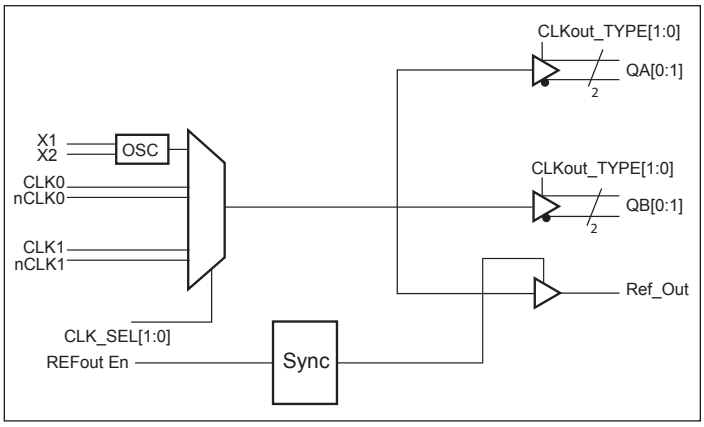
Description

The DIODES PI6C492150xTQ is an automotive high-performance LVDS fanout buffer device which supports up to 1.5GHz frequency. This device is ideal for systems that need to distribute low-jitter clock signals to multiple destinations.

Application(s)

- Networking Systems, including Switches and Routers
- High-Frequency Backplane-based Computing and Telecom Platforms
- ADAS
- Automotive Infotainment

Block Diagram



Features

- 2/4 LVDS Outputs with 2 Banks
- Supports LVPECL, LVDS, HCSL, CML, CMOS or Crystal Input
- LVCMOS Reference Output Up to 200MHz
- Up to 1.5GHz Output Frequency for Differential Outputs
- Ultra-low Additive Phase Jitter: <0.03ps (Differential 156.25MHz, 12KHz to 20MHz Integration Range)
- Selectable Reference Inputs Support Either Single-Ended or Differential or Xtal
- Low Skew Between Outputs within Banks (<40ps)
- Low Delay from Input to Output (Tpd typical <1.5ns)
- Separate Input Output Supply Voltage for Level Shifting
- 2.5V / 3.3V Power Supply
- AEC-Q100 Qualified, Automotive Grade 1 Support
- Ambient Operating Temperature: -40°C to 125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The PI6C492150xTQ is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.
  https://www.diodes.com/quality/product-definitions/
- Packaging (Pb-free & Green):
  - 32-pin WQFN (ZHW)

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Automotive products are AEC-Q100 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.

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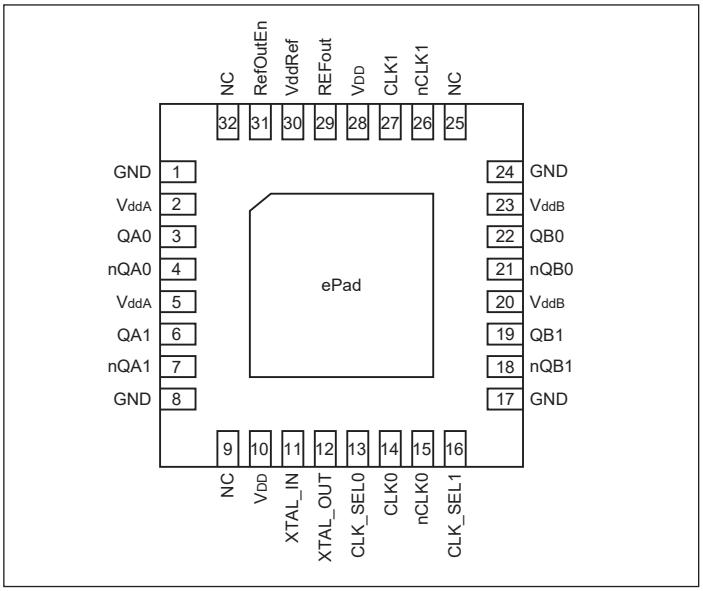
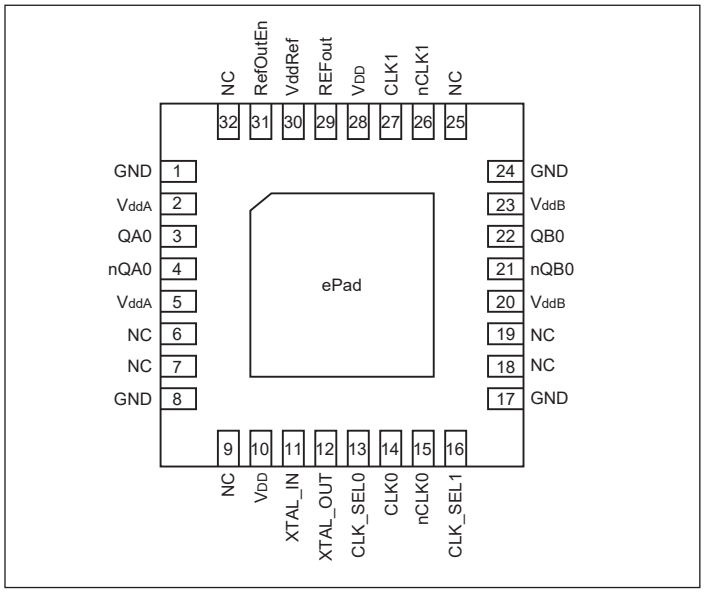
Pin Configuration

PI6C4921504TQ



PI6C4921502TQ



Pin Description

PI6C4921504TQ Pin #	PI6C4921502TQ Pin#	Pin Name	Type	Description
1, 8, 17, 24	1, 8, 17, 24	GND	Power	Negative power supply
9, 25, 32	6, 7, 9, 18, 19, 25, 32	NC	-	Not Connect
2, 5	2, 5	V_{ddA}	Power	Power supply for Bank A Output buffers. V_{ddA} operates from 3.3V or 2.5V
13	13	CLK_SEL0	Input	Clock input source selection pin
16	16	CLK_SEL1	Input	Clock input source selection pin
14, 15	14, 15	CLK0 nCLK0	Input	Differential clock input
27, 26	27, 26	CLK1 nCLK1	Input	Differential clock input
11	11	XTAL_In	Input	Input for crystal, XO, or single ended clock
12	12	XTAL_Out	Output	Output for crystal. Leave Xtal_Out floating if Xtal_In is driven by a single ended clock
10, 28	10, 28	V_{DD}	Power	Power supply for core
18, 19	–	nQB1 QB1	Output	Differential output clock
21, 22	21, 22	nQB0 QB0	Output	Differential output clock

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PI6C4921504TQ Pin #	PI6C4921502TQ Pin#	Pin Name	Type	Description
29	29	Ref_Out	Output	Reference output clock
7, 6	–	nQA1 QA1	Output	Differential output clock
4, 3	4, 3	nQA0 QA0	Output	Differential output clock
ePad	ePad	ePad	GND	Connect to the PCB ground
20, 23	20, 23	V_{ddB}	Power	Power supply for Bank B Output buffers. V_{ddB} operates from 3.3 V or 2.5V
30	30	VddRef	Power	Power supply for reference clock output
31	31	RefOutEn	Input	REFout enable input

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Function Table

Table 1: Input Selection

CLK_SEL1	CLK_SEL0	Selected Input
0	0	CLK0, nCLK0
0	1	CLK1, nCLK1
1	X	XTAL_In

Table 2: Reference Output Enable

REFout_EN	REFout STATE
0	Disabled (Hi-Z)
1	Enabled

Table 3: CLKx Input vs. Output States

State of Selected Input Clock	State of Enabled Outputs
CLKx and nCLKx Inputs Floating	Logic Low
CLKx and nCLKx Inputs Shorted Together	Not Supported. Output is Undefined
CLKx Logic Low	Logic Low
CLKx Logic High	Logic High

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Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested)

Storage Temperature.....-55 to +150°C
Supply Voltage to Ground Potential ($V_{DD,}$ V_{DDO})... -0.5 to +4.6V
Inputs (Referenced to GND) ..... -0.5 to V_{DD}+0.5V
Clock Output (Referenced to GND)..... -0.5 to V_{DD}+0.5V
Latch Up 200mA
ESD Protection (Input) ..... 2000V min (HBM)
Junction Temperature ..... 150 °C max

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Power Supply Characteristics and Operating Conditions

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
V_{DD}	Core Supply Voltage		2.375		3.465	V
V_{DDO}	Output Supply Voltage	$V_{DDO} \le V_{DD}$	2.375		3.465	V
I_{DD}	Core Power Supply Current	All LVDS Loaded		50	65	mA
I_{DDO}	Output Power Supply Current	All LVDS Loaded		35	46	
T_A	Ambient Operating Temperature(1)	LVDS output	-40		125	°C

Note:

1. Either T_A used as operating condition

DC Electrical Specifications - Differential Inputs

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
I_{IH}	Input High current	Input = V_{DD}			150	uA
I_{IL}	Input Low current	Input = GND	-150			uA
C_{IN}	Input capacitance			3		PF
V_{IH}	Input high voltage				V_{DD}+0.3	V
V_{IL}	Input low voltage		-0.3			V
V_{ID}	Input Differential Amplitude PK-PK		0.15		1.3	V
V_{CM}	Common model input voltage		0.25		V_{DD}-1.2	V
ISO_{MUX}	MUX isolation			-89		dBc

DC Electrical Specifications - LVCMOS Inputs

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
I_{IH}	Input High current	Input = V_{DD}			150	uA

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Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
I_{IL}	Input Low current	Input = GND	-150			uA
V_{IH}	Input high voltage	V_{DD} = 3.3V	2.0		V_{DD}+0.3	V
V_{IL}	Input low voltage	V_{DD} = 3.3V	-0.3		0.8	V
V_{IH}	Input high voltage	V_{DD} = 2.5V	1.7		V_{DD}+0.3	V
V_{IL}	Input low voltage	V_{DD} = 2.5V	-0.3		0.7	V

DC Electrical Specifications- LVDS Outputs

Parameter	Description	Conditions	Min.	Typ.	Max.	Units
V_{OH}	Output High voltage		1.4	1.5	1.6	V
V_{OL}	Output Low voltage		1	1.1	1.25	V
Vocm	Output commode voltage		1.2	1.3	1.45	V
DVocm	Change in Vocm between completely output states				50	mV

DC Electrical Specifications – LVCMOS Outputs

Parameter	Description	Conditions	Min.	Typ.	Max.	Units
V_{OH}	Output High voltage	V_{DDO} = 3.3V +/-5%, I_{OH} = -8mA	2.3			V
		V_{DDO} = 2.5V +/- 5%, I_{OH} = -8mA	1.5			V
V_{OL}	Output Low voltage	V_{DDO} = 3.3V +/-5%, I_{OL} = 8mA			0.5	V
		V_{DDO} = 2.5V +/- 5%, I_{OL} = 8mA			0.4	V
V_{OH}	Output High voltage	V_{DDO} = 3.3V +/-5%, I_{OH} = -24mA	2.1			V
		V_{DDO} = 2.5V +/- 5%, I_{OH} = -16mA	1.5			V
V_{OL}	Output Low voltage	V_{DDO} = 3.3V +/-5%, I_{OL} = 24mA			1	V
		V_{DDO} = 2.5V +/- 5%, I_{OL} = 16mA			0.8	V

AC Electrical Specifications – LVDS Outputs

Parameter	Description	Conditions		Min.	Typ.	Max.	Units
F_{OUT}	Clock output frequency	LVDS				1500	MHz
T_r	Output rise time	From 20% to 80%	LVDS	100	150	300	ps
T_f	Output fall time	From 80% to 20%	LVDS	100	150	300	ps

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Parameter	Description	Conditions		Min.	Typ.	Max.	Units
T_{ODC}	Output duty cycle	Frequency < 650MHz, $V_{ID} \geq 400mV$	LVDS	47		53	%
		Frequency < 1GHz, $V_{ID} \geq 400mV$	LVDS	45		55	
		Frequency < 1.5GHz, $V_{ID} \geq 400mV$	LVDS	40		60	
V_{PP}	Output swing Single-ended	LVDS outputs @ <1GHz		250		600	mV
		LVDS outputs @ >1GHz		250		550	
T_j	Buffer additive jitter RMS	156.25MHz, 12kHz to 20MHz			0.02		ps
		156.25MHz, 10kHz to 1MHz			0.01		ps
T_{SK}	Output Skew	4 outputs devices, outputs in same bank, with same load, at DUT.			15	40	ps
T_{PD}	Propagation Delay	LVDS @ 3.3V, 100MHz			570		ps
T_{OD}	Valid to HiZ					200	ns
T_{OE}	HiZ to valid					200	ns
$T_{P2P\ Skew}$	Part to Part Skew(1)				80	120	ps

AC Electrical Specifications – CMOS

(Operating Temperatures -40°C to 125°C)

Parameter	Description	Conditions	Min.	Typ.	Max.	Units
F_{OUT}	Ref_Out frequency	XTAL input	10		50	MHz
		Reference input			200	MHz
T_j	Buffer additive jitter RMS	XTAL input		0.3		ps
		Reference input		0.03		ps
t_r / t_f	Rise time, Fall time	C_L = 5pF		0.8		ns
T_{ODC}	Output duty cycle	C_L = 5pF 3.3V, max test freq. 200MHz 2.5V, max test freq. 150MHz	45		55	%
t_{PD}	Propagation delay	3.3V, 25MHz		4500		ps
t_S	Setup time		300			ps
t_{SOD}	Clock edge to output disable	Ref_Out	2		4	cycles
t_{SOE}	Clock edge to output enable	Ref_Out	2		4	cycles
R_{IUT}	Output Impedance	V_{DDO} = 3.3V ± 5%		30		Ω
		V_{DDO} = 2.5V ± 5%		45		Ω

Notes:

1. This parameter is guaranteed by design

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Crystal Characteristics

Parameter	Min.	Typ.	Max.	Units
Mode of Oscillation		Fundamental		
Frequency Range	10		50	MHz
Equivalent Series Resistance (ESR)			70	Ω
Shunt Capacitance			7	pF
Load Capacitance	10		18	pF
Drive Level			500	µW

Recommended Crystals

Diodes Recommends:

a) GC2500003 XTAL 49S/SMD(4.0 mm), 25M, CL=18pF, +/-30ppm
http://www.pericom.com/pdf/datasheets/se/GC_GF.pdf

b) FY2500091, SMD 5x3.2(4P), 25M, CL=18pF, +/-30ppm
http://www.pericom.com/pdf/datasheets/se/FY_F9.pdf

c) FL2500047, SMD 3.2x2.5(4P), 25M, CL=18pF, +/-20ppm
http://www.pericom.com/pdf/datasheets/se/FL.pdf

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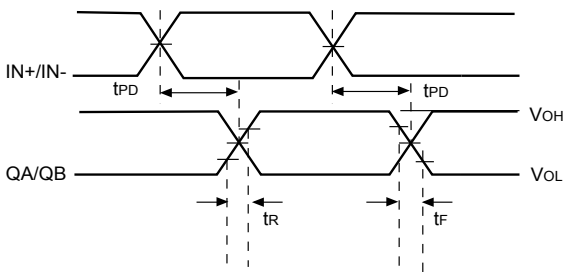
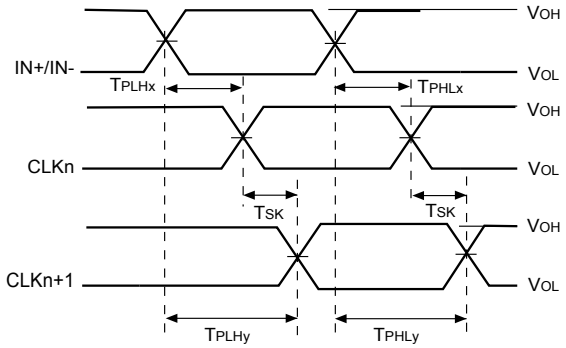
Propagation Delay (T_{PD})



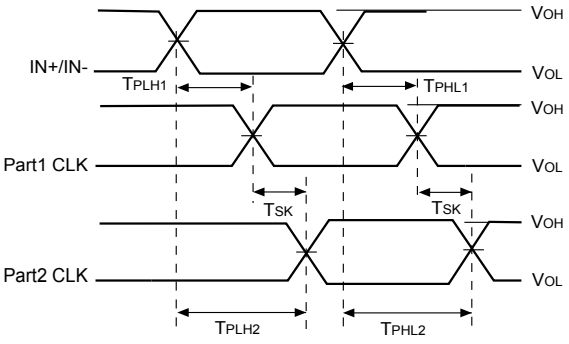
$T_{SK} = T_{PLH2} - T_{PLH1}$ or $T_{SK} = T_{PHL2} - T_{PHL1}$

Output Skew (TSK)



$T_{SK} = T_{PLHy} - T_{PLHx}$ or $T_{SK} = T_{PHLy} - T_{PHLx}$

Part to Part Skew



$T_{SK} = T_{PLH2} - T_{PLH1}$ or $T_{SK} = T_{PHL2} - T_{PHL1}$

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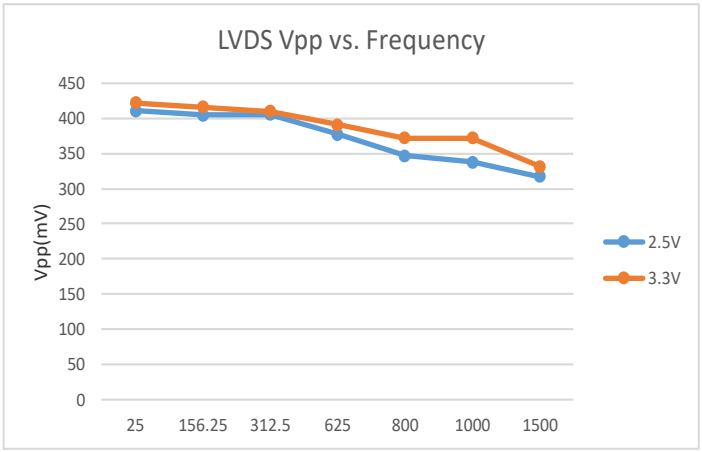
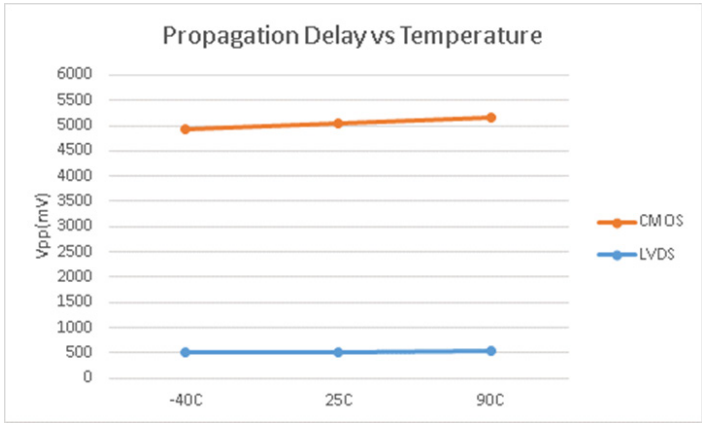
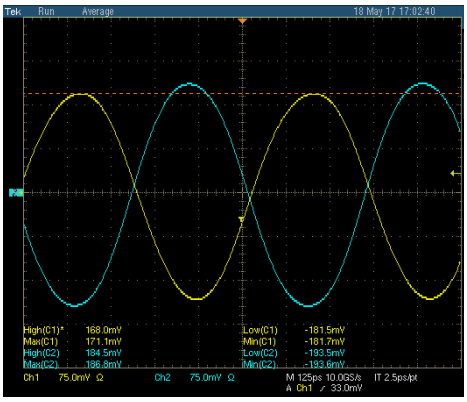
LVDS Output Swing vs. Frequency



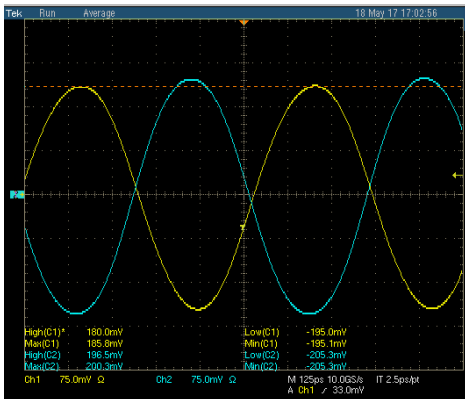
Propagation Delay vs Temperature



1.5GHz LVDS Waveform



2.5V LVDS Waveform



3.3V LVDS Waveform

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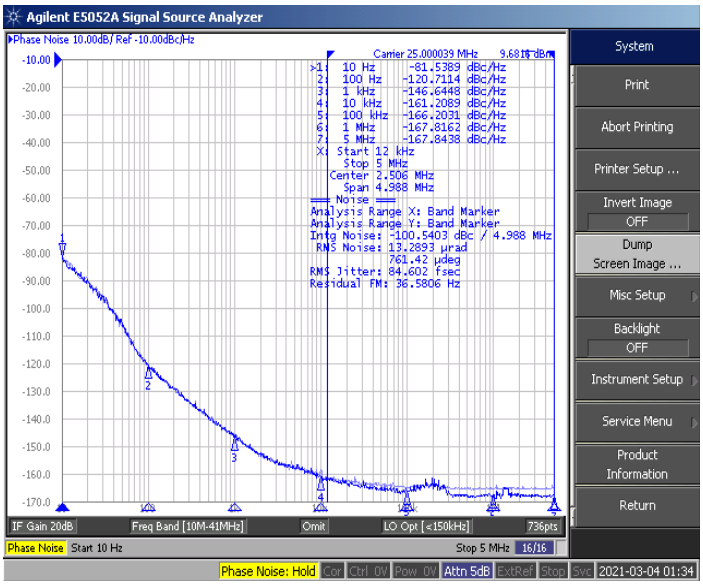
Phase Noise and Additive Jitter

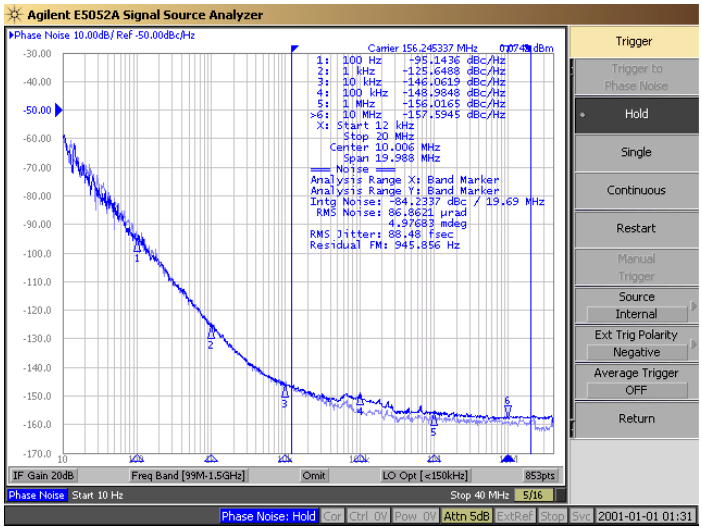
Output phase noise (Dark Blue) vs Input Phase noise (light blue)

Additive jitter is calculated at 25MHz ~71fS RMS (12kHz to 5MHz). Additive jitter = $\sqrt{(\text{Output jitter}^2 - \text{Input jitter}^2)}$

Ref_out 25MHz Phase Noise Plot, VDD=VDDO=3.3V, 25°C , Driven by 25MHz CMOS XO



156.25M LVDS Output Additive Jitter Noise Plot, 3.3V



3.3V LVDS Output Jitter 88fs vs. Input 72fs

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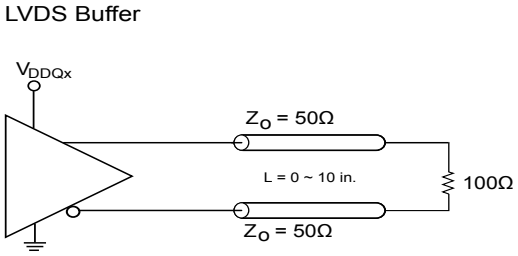
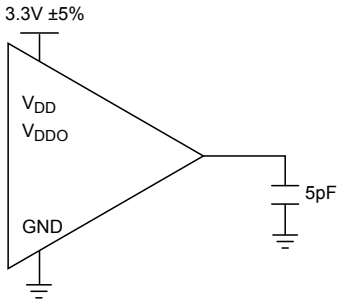
Configuration Test Load Board Termination for LVDS Outputs



Configuration Test Load Board Termination for LVCMOS Outputs



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Application Information

Wiring the differential input to accept single ended levels

Figure 1 shows how the differential input can be wired to accept single ended levels. The reference voltage V_REF = V_{DD}/2 is generated by the bias resistors R1, R2 and C1. This bias circuit should be located as close as possible to the input pin. The ratio of R1 and R2 might need to be adjusted to position the V_REF in the center of the input voltage swing. For example, if the input clock swing is only 2.5V and V_{DD} = 3.3V, V_REF should be 1.25V and R2/R1 = 0.609.

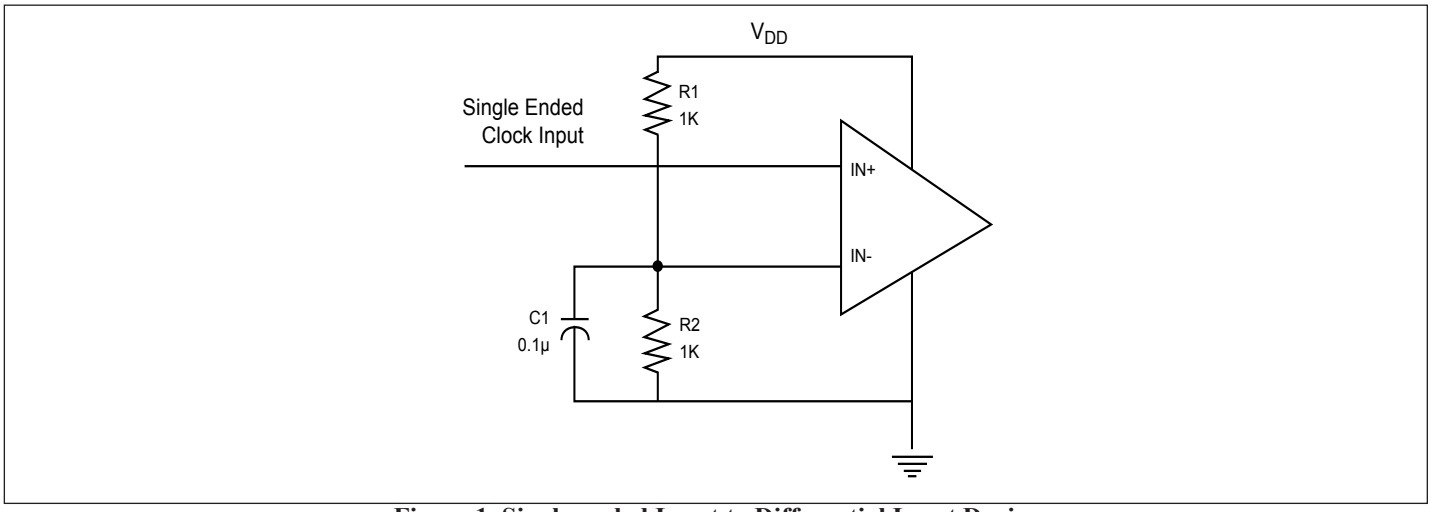
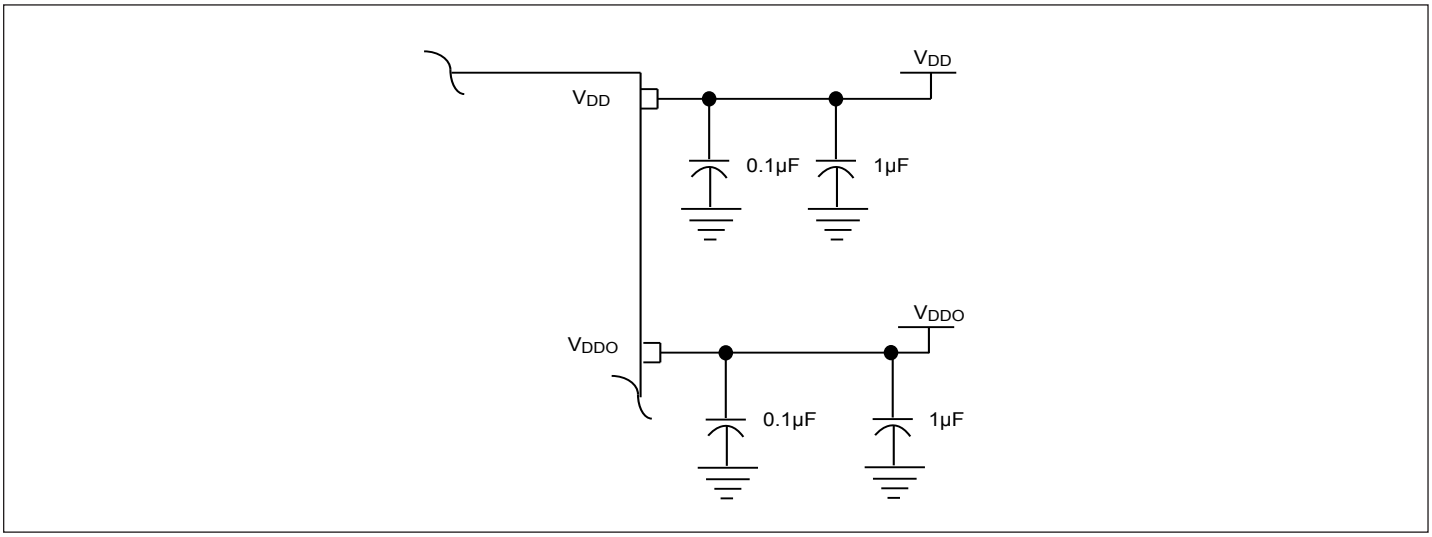


Figure 1. Single-ended Input to Differential Input Device

Power Supply Filtering Techniques

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. All power pins should be individually connected to the power supply plane through vias, and 0.1µF an 1µF bypass capacitors should be used for each pin.



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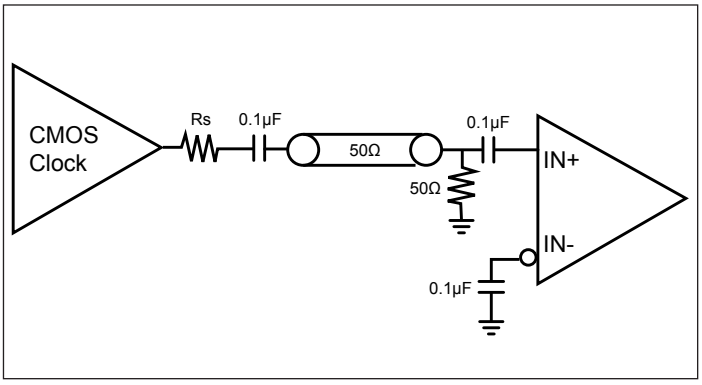
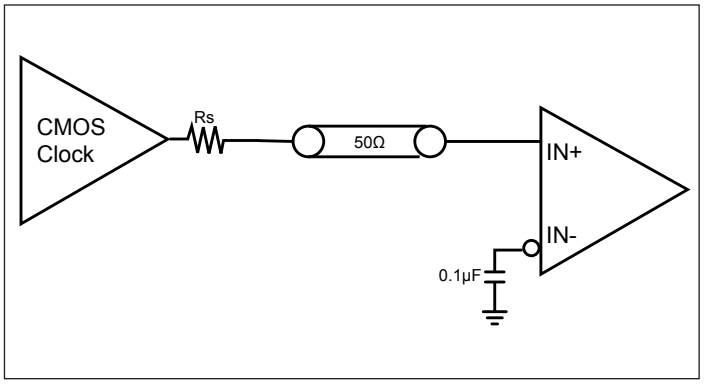
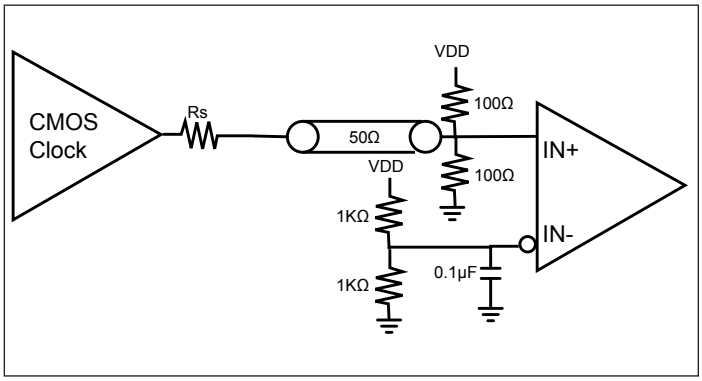
Single Ended Input, AC Couple



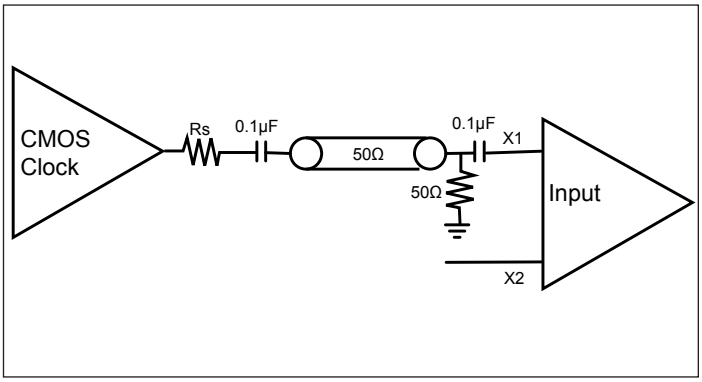
Single Ended Input, DC Couple



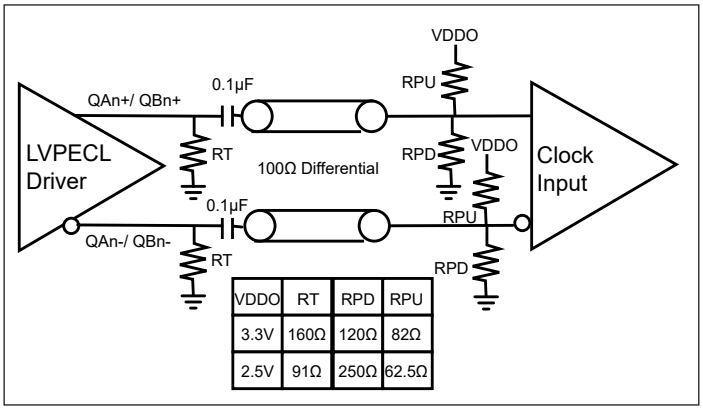
Single Ended Input, DC Couple



Driving X1 with a Single Ended Input

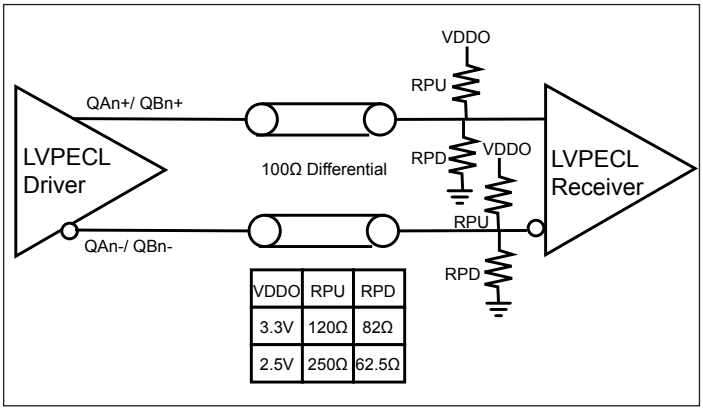


LVPECL, AC Couple, Thevenin Equivalent



VDDO	RT	RPD	RPU
3.3V	160Ω	120Ω	82Ω
2.5V	91Ω	250Ω	62.5Ω

LVPECL, DC Couple, Thevenin Equivalent



VDDO	RPU	RPD
3.3V	120Ω	82Ω
2.5V	250Ω	62.5Ω

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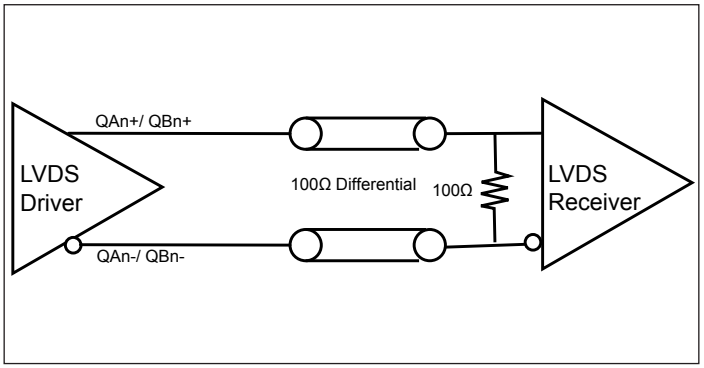
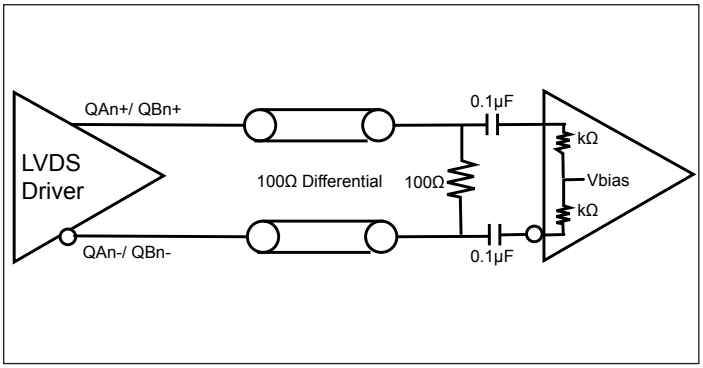
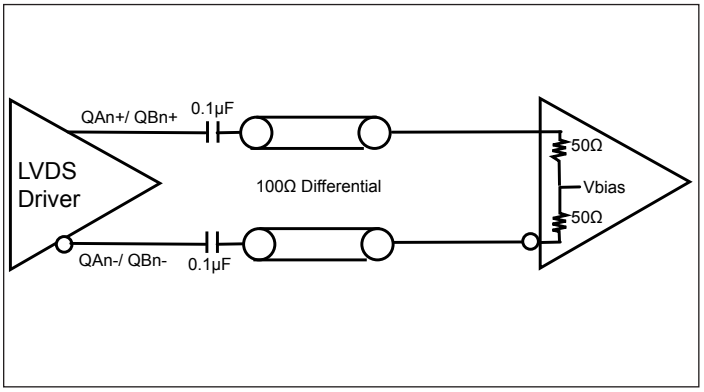
LVDS DC Couple



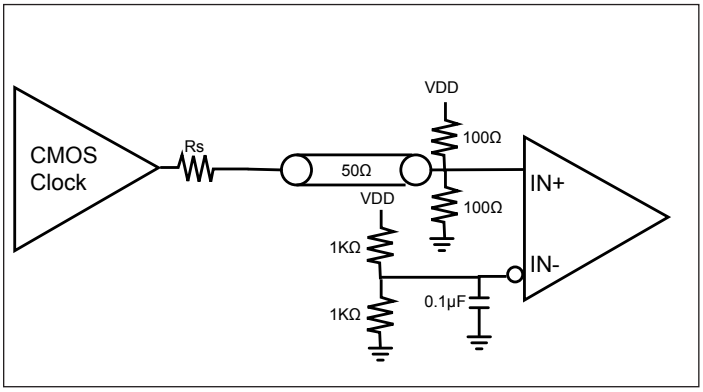
LVDS AC Couple at Load



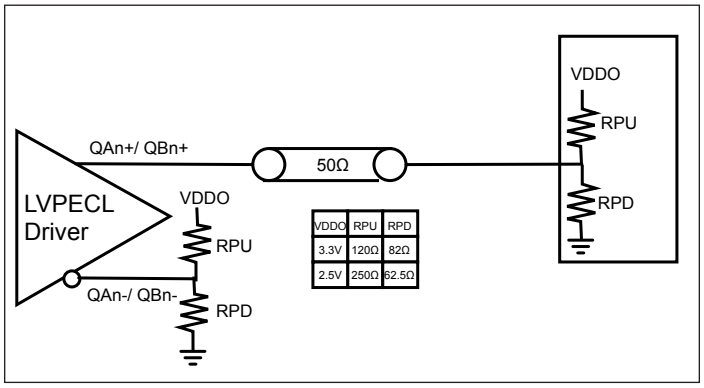
LVDS AC Couple with Internal Termination



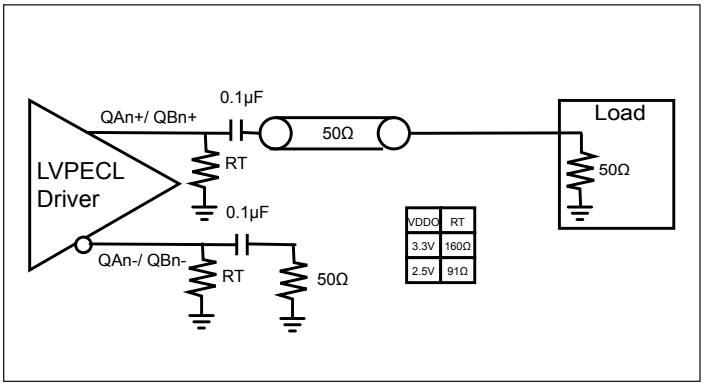
Single Ended LVPECL, DC Couple



Single Ended LVPECL, DC Couple, Thevenin Equivalent



Single Ended LVPECL, AC Couple, Thevenin Equivalent



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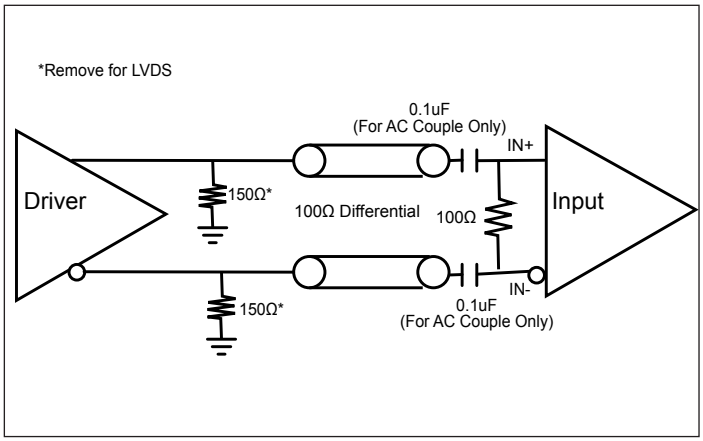
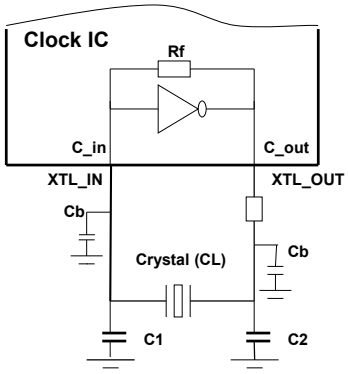
LVPECL/ LVDS AC and DC Input



Clock IC Crystal Input Guide



Part Marking

Top mark not available at this time. To obtain advance information regarding the top mark, please contact your local sales representative.

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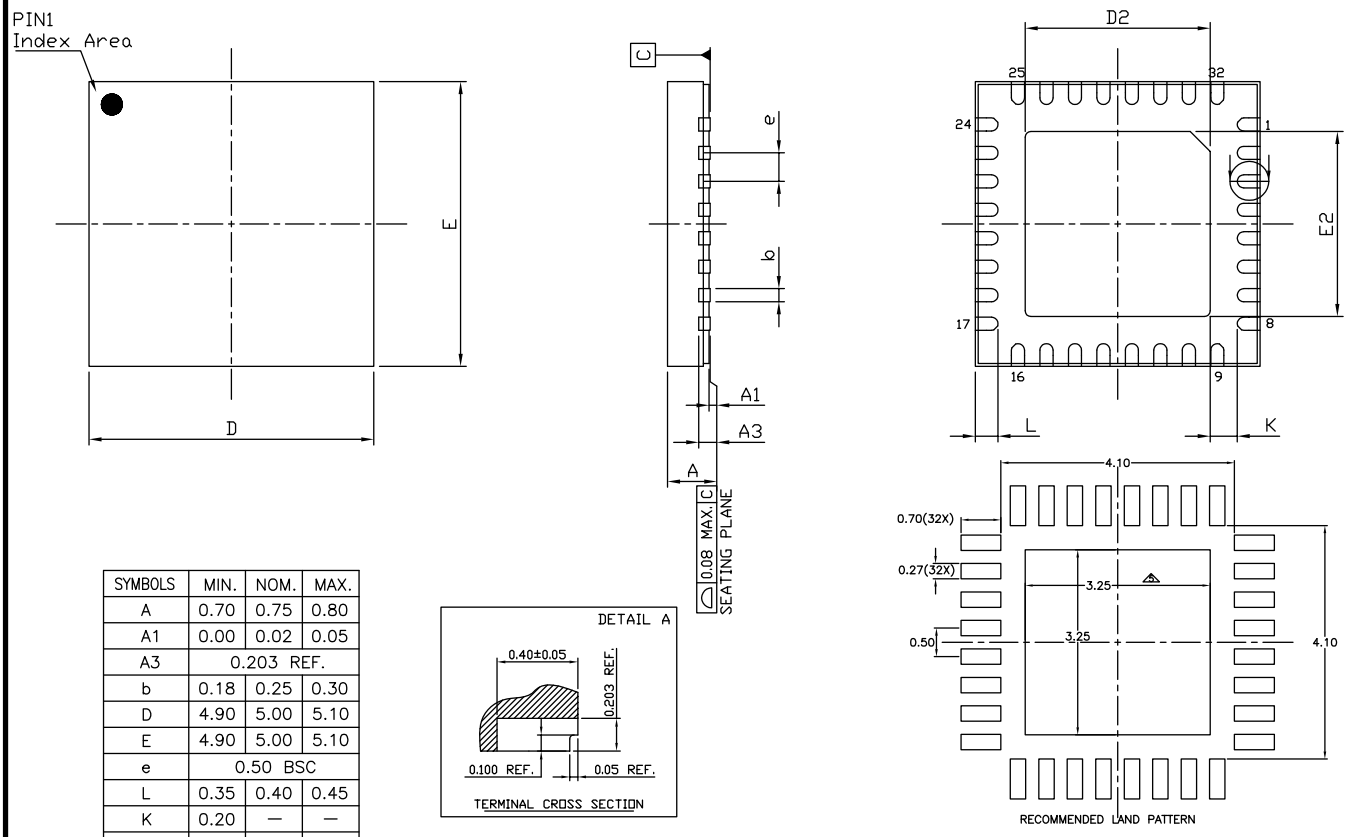
Packaging Mechanical

32-WQFN (ZHW)



SYMBOLS	MIN.	NOM.	MAX.
A	0.70	0.75	0.80
A1	0.00	0.02	0.05
A3		0.203 REF.	
b	0.18	0.25	0.30
D	4.90	5.00	5.10
E	4.90	5.00	5.10
e		0.50 BSC	
L	0.35	0.40	0.45
K	0.20	—	—
D2	3.20	3.25	3.30
E2	3.20	3.25	3.30

NOTE :
1. ALL DIMENSIONS ARE IN mm. ANGLES IN DEGREES.
2. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
3. REFER JEDEC MO-220.
4. RECOMMENDED LAND PATTERN IS FOR REFERENCE ONLY.
5. THERMAL PAD SOLDERING AREA (MESH STENCIL DESIGN IS RECOMMENDED)
6. SWP STANDS FOR SIDEWALL PLATING

DATE: 05/20/22

DESCRIPTION: W-QFN5050-32 (SWP)

PACKAGE CODE: ZHW (ZHW32)

DOCUMENT CONTROL #: PD-2277 REVISION: --

For latest package info.
please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Ordering Code	Package Code	Package Description	Operating Temperature
PI6C4921502TQ1ZHWEX	ZHW	32-contact, W-QFN5050-32 (SWP)	-40°C to 125°C
PI6C4921504TQ1ZHWEX	ZHW	32-contact, W-QFN5050-32 (SWP)	-40°C to 125°C

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Q = Automotive Compliant
5. 1 = AEC-Q100 Grade Level
6. E = Pb-free and Green
7. X suffix = Tape/Reel

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